

TO-92MOD Plastic-Encapsulate Transistors

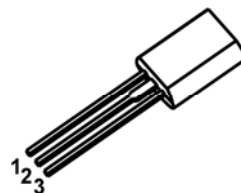
BD034 TRANSISTOR (PNP)

FEATURES

- Power Supplies, Relay Drivers, Lamp Drivers, and Automotive Wiring.

TO - 92MOD

- EMITTER
- COLLECTOR
- BASE



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-110	V
V_{CEO}	Collector-Emitter Voltage	-95	V
V_{EBO}	Emitter-Base Voltage	-7	V
I_C	Collector Current	-2.5	A
P_C	Collector Power Dissipation	900	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	138	$^{\circ}\text{C}/\text{W}$
T_j	Junction Temperature	150	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~+150	$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^{\circ}\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C = -0.1\text{mA}, I_E = 0$	-110			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C = -10\text{mA}, I_B = 0$	-95			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E = -100\mu\text{A}, I_C = 0$	-7			V
Collector cut-off current	I_{CBO}	$V_{CB} = -100\text{V}, I_E = 0$			-1	μA
Emitter cut-off current	I_{EBO}	$V_{EB} = -5\text{V}, I_C = 0$			-1	μA
DC current gain	$h_{FE(1)}$	$V_{CE} = -2\text{V}, I_C = -100\text{mA}$	100		560	
	$h_{FE(2)}$	$V_{CE} = -2\text{V}, I_C = -1.5\text{A}$	40			
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -2\text{A}, I_B = -200\text{mA}$			-0.5	V
Base-emitter voltage	V_{BE}	$V_{CE} = -5\text{V}, I_C = -500\text{mA}$			-1	V
Transition frequency	f_T	$V_{CE} = -1\text{V}, I_C = -250\text{mA}, f = 1\text{MHz}$	3			MHz

CLASSIFICATION OF $h_{FE(1)}$

RANK	R	S	T	U
RANGE	100-200	140-280	200-400	280-560